TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP521-1, TLP521-2, TLP521-4

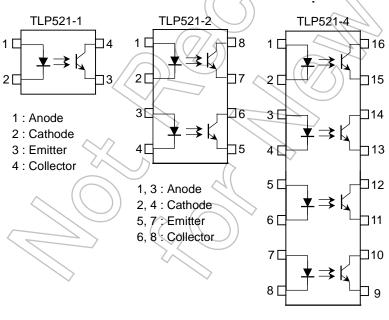
Programmable Controllers AC/DC-Input Module Solid State Relay

The TOSHIBA TLP521-1, -2 and -4 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode.

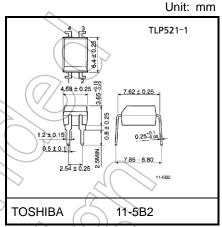
The TLP521-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP521-4 provides four isolated channels in a sixteen plastic DIP package.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min)
 Rank GB: 100% (min)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1577, file no. E67349
- c-UL recognized: CSA Component Acceptance Service No. 5A
 File No.E67349

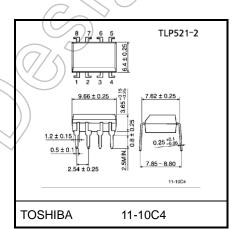
Pin Configurations (top view)



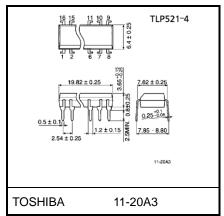
1, 3, 5, 7 : Anode 2, 4, 6, 8 : Cathode 9, 11, 13, 15 : Emitter 10, 12, 14, 16: Collector



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1979-05



Absolute Maximum Ratings (Ta = 25°C)

| | | | Ra | | |
|------------------------------------------------------------------|--------------------------------------------------------------|---------------------|-------------------|----------------------|----------------------------------------|
| | Characteristic | Symbol | TLP521-1 | TLP521-2 TLP521-4 | Unit |
| | Forward current | lF | 70 | 50 | mA |
| Q | Forward current derating | ΔI _F /°C | -0.93 (Ta ≥ 50°C) | -0.5 (Ta ≥ 25°C) | mA/°C |
| | Pulse forward current (100 µs pulse, 100 pps) | IFP | 1 | | A |
| 凹 | Reverse voltage | VR | | 5 | \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ |
| | Diode power dissipation | PD | 150 | 100 | ⟨mW |
| | Diode power dissipation derating | ΔP _D /°C | -2.0 (Ta ≥ 50°C) | -1.0 (Ta ≥ 25°C) | mW/°C |
| | Junction temperature | Tj | 125 | | °C |
| | Collector-emitter voltage | VCEO | 55 | | V |
| | Emitter-collector voltage | VECO | 7 | | V |
| j | Collector current | Ic | 50 | | mA) |
| Detector | Collector power dissipation (1 circuit) | Pc | 10 | mW | |
| | Collector power dissipation derating (1 circuit) (Ta ≥ 25°C) | ΔP _C /°C | | mW/°C | |
| | Junction temperature | Tj | |)¢ | |
| Stor | age temperature range | T _{stg} | -55 to | ိုင | |
| Оре | erating temperature range | T _{opr} | -55 to | °C | |
| Lead soldering temperature (10 s) | | T _{sol} | 260 | | °C |
| Total package power dissipation (1 circuit) | | PT | 250 | 150 | mW |
| Total package power dissipation derating (1 circuit) (Ta ≥ 25°C) | | ΔΡτ/°C | -2.5 | 1.5 | mW/°C |
| Isolation voltage (AC, 60 s, R.H.≤ 60%) (Note 1) | | BVs | 25 | 000 | Vrms |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

| Characteristic | Symbol | Min | Тур. | Max | Unit |
|-----------------------|--------|-----|------|-----|------|
| Supply voltage | Vcc | _ | 5 | 24 | V |
| Forward current | lF | _ | 16 | 25 | mA |
| Collector current | Ic | _ | 1 | 10 | mA |
| Operating temperature | Topr | -25 | _ | 85 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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Current transfer ratio

| | Classi- | | sfer Ratio (%) /I _F) | Marking Of | | | |
|-----------|----------|-------------------------------|-------------------------------------|---------------------------------------------------------------|--|--|--|
| Туре | fication | IF = 5mA, VCE = 5V, Ta = 25°C | | Marking Of Classification | | | |
| | (Note 1) | Min | Max | | | | |
| | Blank | 50 | 600 | Blank, Y [*] , YE, G, G [*] , GR, B, BL, GB | | | |
| | Rank Y | 50 | 150 | YE, Y⁼ | | | |
| | Rank GR | 100 | 300 | GR, G, G■ | | | |
| | Rank BL | 200 | 600 | BL, B | | | |
| TLP521-1 | Rank GB | 100 | 600 | GB, GR, G, G [■] , BL, B | | | |
| | Rank YH | 75 | 150 | Υ• | | | |
| | Rank GRL | 100 | 200 | G | | | |
| | Rank GRH | 150 | 300 | G* | | | |
| | Rank BLL | 200 | 600 | В | | | |
| | Blank | 50 | 600 | Blank, GR, BL, GB | | | |
| TLP521-2 | Rank GB | 100 | 600 | GB, GR, BL | | | |
| 1LP521-2 | Rank GR | 100 | 300 | GR | | | |
| | Rank BL | 200 | 600 | BL | | | |
| TI D504 4 | Blank | 50 | 600 | Blank, GB | | | |
| TLP521-4 | Rank GB | 100 | 600 | GB (7/4) | | | |

Note 1: Ex. rank GB: TLP521-1 (GB)

Note: Application type name for certification test, please use standard product type name, i.e. TLP521-1 (GB): TLP521-1, TLP521-2 (GB): TLP521-2





Electrical Characteristics (Ta = 25°C)

| | Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------|-------------------------------------|-----------------------------------|-------------------------|-----|------|-----|------|
| | Forward voltage | VF | IF = 10 mA | 1.0 | 1.15 | 1.3 | V |
| LED | Reverse current | I _R | V _R = 5 V | _ | _ | 10 | μA |
| | Capacitance | CT | V = 0 V, f = 1 MHz | 7 | 30 | | pF |
| | Collector-emitter breakdown voltage | V _(BR) CEO | I _C = 0.5 mA | 55 | _ | _ | V |
| jo | Emitter-collector breakdown voltage | V _{(BR)ECO} | I _E = 0.1 mA | X |) /_ | | V |
| Detector | Collector dark current | V _{CE} = 24 V |) | 10 | 100 | nA | |
| | Collector dark current | V _{CE} = 24 V, Ta = 85°C | | 2 | 50 | μA | |
| | Capacitance (collector to emitter) | C _{CE} | V = 0 V, f = 1 MHz | | 10 | | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | > Max | Unit |
|------------------------|------------|-----------------------------------------------------------|-----|---------|-------|------|
| Current transfer ratio | IC/IF | I _F = 5 mA, V _{CE} = 5 V Rank GB | 50 | | 600 | % |
| Saturated CTR | IC/IF(sat) | I _F = 1 mA, V _{GE} = 0.4 V Rank GB | 30 | 60 — | _ | % |
| Collector-emitter | VCE(sat) | IC = 2.4 mA, I _F = 8 mA |) – | 0.2 | 0.4 | V |
| saturation voltage | · OE(sat) | Ic = 0.2 mA, I _F = 1 mA Rank GB | _ | — — | 0.4 | • |

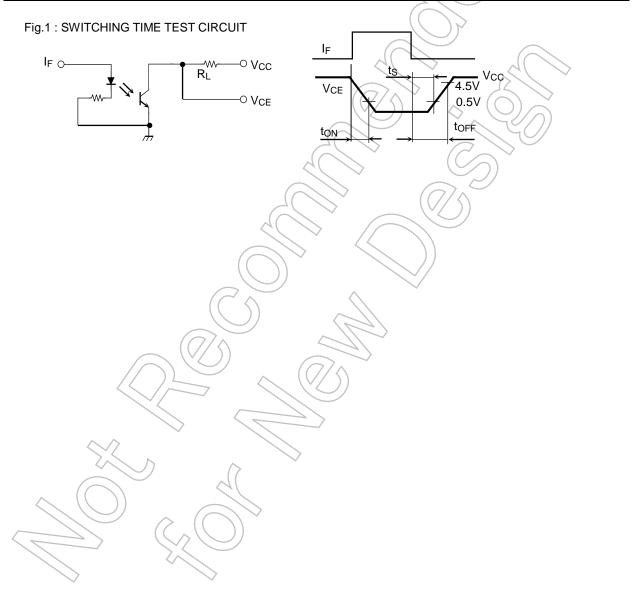
Isolation Characteristics (Ta = 25°C)

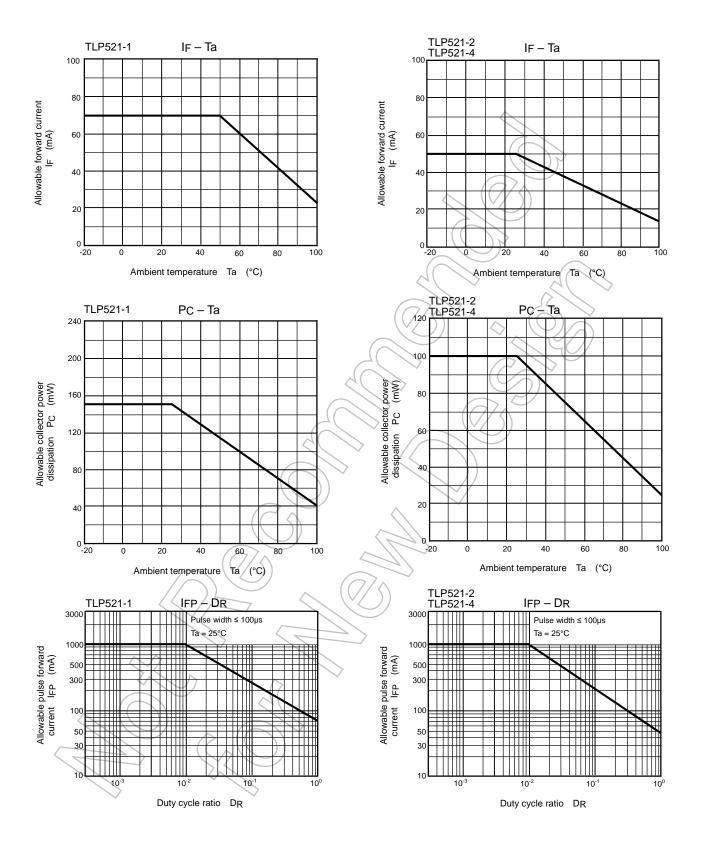
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------|--------|-----------------------------------|--------------------|------------------|-----|--------|
| Capacitance (input to output) | Cs | $V_S = 0$ $V, f = 1$ MHz | | 0.8 | l | pF |
| Isolation resistance | Rs | V _S = 500 V, R.H.≤ 60% | 5×10 ¹⁰ | 10 ¹⁴ | | Ω |
| | | AC, 60 s | 2500 | _ | _ | Vrms |
| Isolation voltage | BVS | AC, 1 s, in oil | _ | 5000 | _ | VIIIIS |
| | | DC, 60 s, in oil | _ | 5000 | _ | Vdc |

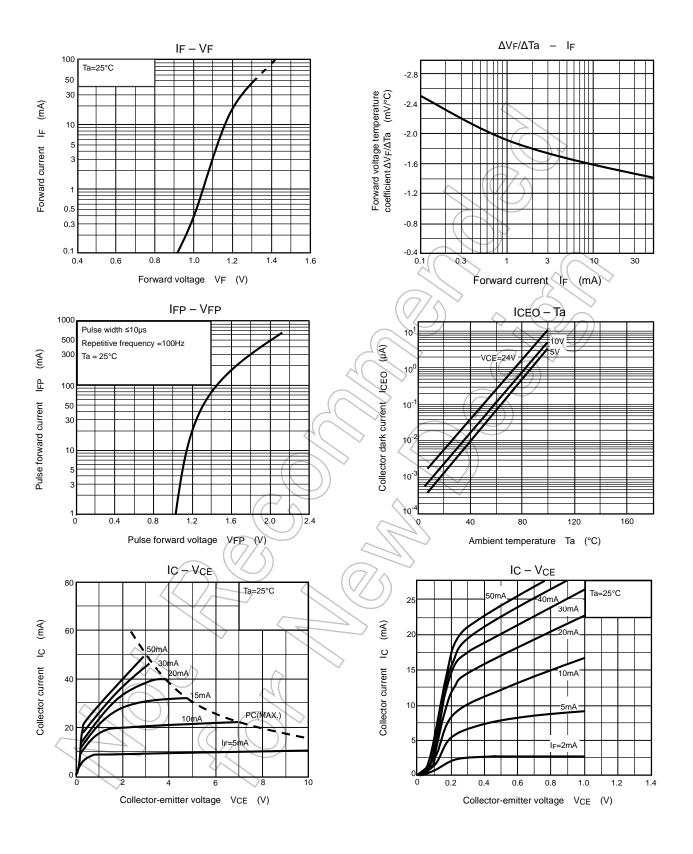


Switching Characteristics (Ta = 25°C)

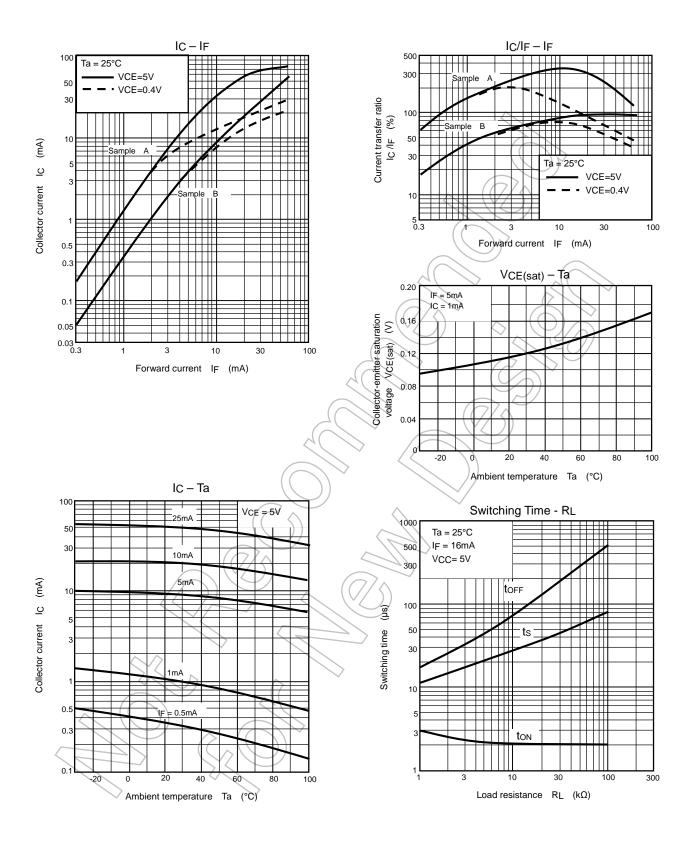
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------|------------------|------------------------------------------------------------------------------------|--------------|-------|-----|------|
| Rise time | tr | | _ | 2 | _ | |
| Fall time | tf | Vcc = 10 V | _ | 3 | _ | |
| Turn-on time | t _{on} | $I_C = 2 \text{ mA}$ $R_L = 100\Omega$ | 7 | 3 | _ | μs |
| Turn-off time | t _{off} | | (-) | 3 | _ | |
| Turn-on time | ton | | 1 |) / 2 | _ | |
| Storage time | ts | $R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V, I}_F = 16 \text{ mA}$ |) <u> </u> | 15 | _ | μs |
| Turn-off time | tOFF | | $\bigcirc)$ | 25 | | |







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